NSN 5961-01-235-4125

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-235-4125 **Inclosure Material:** Metal **Overall Length:** 1.250 inches **Overall Height:** 0.295 inches **Overall Width:** 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -100.0 breakdown voltage, collector-to-base, emitter open and -100.0 breakdown voltage, collector-to-emitter, base open and -6.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** -2.00 amperes source cutoff current and 0.80 amperes source cutoff current **Power Rating Per Characteristic:** 16.6 watts small-signal input power, common-collector preset **Transfer Ratio:** 30.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure:**

No Fiig:

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Demilitarization: